The e ective S-m atrix from conductance data in a quantum wave guide: D istinguishing the indistinguishable

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We consider two di erent stationary random processes whose probability distributions are very close and indistinguishable by standard tests for large but limited statistics. Yet we demonstrate that these processes can be reliably distinguished. The method is applied to analyze conductance uctuations in coherent electron transport through nanostructures.

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The quantum -m echanical scattering by complex system s has been a problem of long-standing interest. This problem is of a great importance in nuclear, molecular and mesoscopic physics [1, 2, 3, 4]. The scattering process can be often analyzed in terms of two distinct time scales: (i) a prompt response due to direct processes and (ii) a time-delayed scattering mechanism. In nuclear physics the tim e-delayed m echanism is associated with the form ation of an equilibrated compound nucleus [1, 5]. Sim ilarly, tim e-delayed processes have been encountered in the study of coherent electron transport through nanostructures [1, 2, 3, 4, 6]. The two distinct tim e scales introduce two di erent energy scales. Nam ely, the scattering am plitude of direct processes is a sm ooth function of energy and it can be taken as an energy averaged S-m atrix. The scattering am plitude of tim e-delayed process, on the other hand, is an energy dependent function which uctuates rapidly around zero. K now ledge of the energy averaged S-m atrix allows one to construct a probability distribution (PD) of the fulls -m atrix [6,7,8].

S-matrix for ballistic electron scattering o nanostructures can be calculated num erically if the geom etry of the nanodevice, as well as the shape, size and num ber of propagating m odes of the leads, and spatial distribution of disorder are known precisely. Then, having calculated the energy dependence of the S-m atrix one can directly separate it into an energy averaged direct reaction com ponent and a uctuating one. In experiments, the detailed information about the conducting device may not be always available. For example, wall in perfections and unknown spacial distribution of disorder does not allow to evaluate the contribution of direct processes. D isorder can also block leads in an unknown manner reducing the number of propagating modes. This motivates us to consider the \inverse problem ": W hat inform ation about relative contributions of direct and tim e-delayed processes and num ber of propagating m odes in the leads

can be obtained from the analysis of the transmission energy uctuations provided the above mentioned characteristics of the nanodevice are unknown?

For concreteness we consider the transm ission between horizontally oriented leads for the two types of geom etry of wave guides (WG) (Fig. 1). For experimental purposes, we refer the reader to reference [9] for a possible implementation of this system. The left leads of both W G can accom m odate a single propagating channel only. For the W G (b) the right lead also accom m odates only one channel (N = 1), while for W G (a) it has N 2 open channels. In addition, both WG (a) and (b) have Na $1 \text{ and } N_{\rm b}$ 1 open channels shown by arrows pointing down at the bottom of W G with N $_{a}$ N.Disorder is modeled by scatterers (shown in Fig. 1 in white) having in nitely high potential walls.

Transmission between the horizontally oriented leads for the (a) and (b) W G in Fig. 1 is given by

$$\Gamma(E) = \sum_{j=1}^{X^{N}} \mathfrak{F}_{1j}(E) \mathfrak{f}:$$
(1)

Here S_{1j} (E) are the S-m atrix elements for scattering between left leads 1" and right leads j, and E is electron energy. For the WG (b) in Fig. 1 the sum (1) contain only a single term (N = 1). We use the decom position $S_{1j}(E) = \langle S_{1j} \rangle + S_{1j}(E)$, where $\langle S_{1j} \rangle$ are energy averaged S-m atrix elements, and $~S_{1\,j}$ (E) are energy uctuating ones. We chose the spacial distribu-_ij< S_{1j} > ĵ tion of disorder such that (i) 1, and (ii) transm ission between the horizontal leads and open channels at the bottom of both (a) and (b) W G in Fig. 1 is mostly due to tim e-delayed processes. Therefore, the overall am ount of direct processes for the transm ission between di erent channels is much less than that for the overall am ount of tim e-delayed processes. A lso, due to the presence of disorder, the dynam ics of the classical



FIG.1: The electron probability distribution inside the wave guides for an arbitrary chosen electron energy. The arrows show incident unit current from left and current leaving the system from the right. The white circular regions represent in nite potential barriers. The wave guide (a) does not show direct processes and (b) has direct processes (see text).

counterpart in the interaction region of W G (a) and (b) in Fig. 1 is chaotic. Since the total numbers of open channels, N + N_a + 1 and N + 2, are much greater than unity, we are in the regime of Ericson uctuations when electron resonance states within the W G are overlapping. Then each individual uctuating S-matrix element can be considered as a Gaussian random process. Namely, real and in aginary parts of each individual $S_{1j}(E)$ in sum (1) are distributed by a Gaussian law, are uncorrelated and have the same dispersions [1, 5].

The PD for $y = T (E) = \langle T (E) \rangle$ (so that $\langle y \rangle = 1$) is given by [5],

$$P_{N}(y) = N (1 \quad y_{i})^{1} (y=y_{i})^{(N-1)=2}$$

$$exp[N (y_{i} + y)=(1 \quad y_{i})]$$

$$I_{N-1} [2N (y_{i}y)^{1=2}=(1 \quad y_{i})]; (2)$$

Here I_N_{1} () is the modi ed Bessel function of (N $_{j}$) order and $y_d = \int_{j} j < S_{1j} > \hat{j} = < T (E) > is the relative contribution of direct processes to the total transmission. The PD of Eq. (2) is exact if all <math display="inline">S_{1j}(E)$ with di erent j are uncorrelated and have the same dispersions. O therwise this PD is an approximation for which N should be understood as an elective number of independent channels $N_{eff} < N$. It is given by the normalized variance of $T(E) = \sum_{j=1}^{N} j S_{1j}(E) \hat{j}:$ $< T(E)^2 > = < T(E) >^2 \quad 1 = 1 = N_{eff}$.

For the W G (b) in Fig. 1 one has to put N = 1 in Eq. (2). For $y_d = 0$, Eq. (2) takes the form of a ²-distribution with 2N degrees of freedom [5]:

$$P_{N}(y) = N[(N)]^{-1}(Ny)^{N-1}\exp((Ny);$$
(3)



FIG.2: The probability distributions of transm ission. The solid lines, with decreasing thicknesses, show the theoretical curves for N = 1, N = 5 (Eq. (2)) and N = 10 (Eq. (3)) channel cases respectively. The histogram is constructed from the num erical data for N = 1 and $y_d = (0.9)^{1-2}$, as an exam – ple. The inset shows a blow up of the transm ission probability distributions dem onstrating that the di erence between them around their m axim a does not exceed 4%.

where (N) is G amma function. Note that the variance of y is given by $\langle y^2 \rangle = 1 = (1 \quad \frac{2}{3}) = N$ [5].

As an example, we consider two possible cases for W G (a) in Fig. 1: (i) N = 10 and $y_d = 0$, the latter due to complete blocking of the direct paths between the leads by disorder, and (ii) N = 5 and $y_d = (0.8)^{1-2}$. Also suppose that, for W G (b), for which N = 1, $y_d = (0.9)^{1-2}$. For the above three sets of N and y_d values the variance of conductance y is the same and equals 0.1. The question is: C an we distinguish these three cases by analyzing PD of y in Eq. (2)?

In Fig. 2 we plot the PD for the three sets of N and y_d . The three distributions are very close. We perform ed a 2 test and found that, even for as many as 28000 independent realizations of y for each of the three cases, the distributions are indistinguishable at a 99% condence level. And, to the best of our know ledge, there is currently no any other statistical test which would allow to distinguish between the three di erent stochastic processes. Yet, in what follows, we show that the problem of distinguishing between these random processes can be solved.

W e will refer to the y as y_i , where the index i stands for di erent independent realizations of the process. Let us transform to new random variables $s_{ij} = (y_i + y_j)=2$, $r_{ij} = (y_i \quad y_j)=2s_{ij}$ with $i \notin j$. One can now easily nd the joint probability distribution K (s;r). The analytical calculations are form ally sim ilar to those of R ef. [10] for the analysis of the correlation between cross section and analyzing power in the regime of Ericson uctuations in



FIG. 3: The plot of $< r^2$ (s) > vs. s corresponding to the same N (shown in inset) and y_d values as those used for the analysis of the probability distributions in Fig. 2. D otted, dashed and dotted-dashed lines are theoretical predictions (Eq. (4).

nuclear reactions. W ithout presenting the explicit result for K (s;r) we point out that, for $y_d = 0$, s and r are statistically independent. On the contrary, for $y_d \notin 0$, s and r correlate, the bigger y_d the stronger this correlation is.

W e calculate < r^2 (s) > :

$$< r^{2}(s) > = [1 \quad I_{2N+3}()=I_{2N-1}()]=(2N+1);$$
 (4)

where = $4N (y_d s)^{1=2} = (1)$ ya), and take into account y_{d}^{2})=N = 0:1. In Fig. 3, we show the constraint (1 < r² (s) > for the three cases. W e have generated 28000 realizations for each case and used all possible i < j combinations for sij and rij. The data in Fig.3 are obtained by dividing the s_{ij} into 5 bins for each case and taking the average of r^2 (s) and s for each bin. It is evident from Fig. 3 that we can distinguish the three cases. The uctuations around the theoretical curves are determ ined by the num ber of realizations. Error bars are calculated num erically from standard deviations of 100 data sets each consisting 28000 y realizations. W e found that it is possible to distinguish the N = 1 and N = 10processes in 97% of cases for 210 realizations of y. This drops to 85% for 140 realizations.

W e apply the new m ethod to distinguish between (a) and (b) in Fig. 1 from the conductance uctuation data. W e implemented a nite element solution of the Schrodinger equation [9, 11]. Calculations were performed on the energy range which allows 5 propagating channels in the right lead for W G (a) in Fig. 1. Both left leads for W G (a) and (b) as well as the right lead for W G (b) in Fig. 1 accomm odate a single channel. In addition, for both (a) and (b) W G in Fig. 1, there are 20-25 propagating channels from the lower part of the devices. A unit current is directed from left. W e are interested in the transm ission probability from the left to the right side. Spacial disorder distribution for W G (a) in Fig. 1 was chosen to block the direct paths between the left and



FIG.4: The plot of $< r^2$ (s) > vs. s for the wave guides shown in Fig.1. The dashed and dotted-dashed lines are theoretical estimates (Eq. (4)) and thin and thick solid lines are numerical calculations for N = 1 (with direct processes) and for N = 5 (without direct processes) cases respectively. The inset shows conductance distributions (lines) for (a) N = 1, with direct processes (Eq. (2)), and (b) N = 5, without direct processes (Eq. (3)). Histogram s are constructed from the numerical data.

right leads, i.e. to maximally suppress direct processes. This was conmed by S-matrix numerical data, which yielded negligible absolute value of the energy averaged S-matrix, and by the fact that the normalized variance of conductance uctuations is close to 0.2. For WG (b) in Fig. 1 the extension of leads into the cavity is adjusted to have relative contribution of direct process $y_d = 0.9$ so that the normalized variance of conductance uctuations is close to 0.2. For both (a) and (b) WG in Fig. 1 we used di erent disorder distributions to increase the statistics. The overall number of independent realizations of transmission values y for each type of geometry in Fig. 1 was around 150.

In Fig. 4 we present PD of y for the (a) and (b) W G of Fig. 1. 2 test does not allow to distinguish the two PD.Yet, from Fig. 4 one can see that for the N = 1 case, in the presence of direct processes, $< r^2$ (s) > strongly increases when s decreases. On the contrary, for the N = 5 case, when direct processes are absent, < r^2 (s) > for s < 1 is close to a constant. We have checked that even for each single con guration of disorder, when we have only about 30-40 independent realizations of the transm ission values for each (a) and (b) W G , $< r^2$ (s) > increases always noticeably faster for the N = 1 case with direct processes as compared to the N = 5 case without direct processes. 0 n the other hand, the rise of $< r^2$ (s) > when s decreases of s for N = 1 with direct processes is much stronger than that predicted by Eq. (4). In order to nd a possible reason for this we analyzed the PD of uctuating S-m atrix elements. We found that (i) S_{11} (E) are not distributed isotropically in the complex plane, (ii) the PD of real and in againary parts of S_{11} (E)

are not Gaussian, and (iii) real and im aginary parts of

 S_{11} (E) are correlated. Therefore, the reason for the discrepancy between the data and theoretical line in Fig. 4 for N = 1 is that the conditions to derive Eq. (4) are not met. Yet, the distribution for transmission is not sensitive to the deviation of the PD of S_{11} (E) from its isotropic G aussian distribution in the com plex plane and correlation between realand im aginary parts of S_{11} (E).

In conclusion, we have suggested a method to distinguish between di erent stationary random processes

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whose PD are very close and indistinguishable by standard tests for large but limited statistics. The method has been applied to analyze conductance uctuations in coherent electron transport through W G.We found that the method proposed here, unlike the analysis of PD of transmission, is sensitive to (i) the deviation of PD of uctuating transmission amplitudes from isotropic G aussian statistics in the complex plane, and (ii) correlations between real and imaginary parts of the uctuating transmission amplitudes.

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